NSN 5961-01-088-8222

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-088-8222
Inclosure Material:
Metal
Overall Length:
0.380 inches
Overall Diameter:
0.505 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
10.00 amperes forward current, total rms horsepower metric
Power Rating Per Characteristic:
0.2 watts small-signal input power, common-collector peak
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Terminal Type And Quantity:
1 case and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0